SURFACE MOUNT DISPLAY

KPSA56-104

SUPER BRIGHT RED

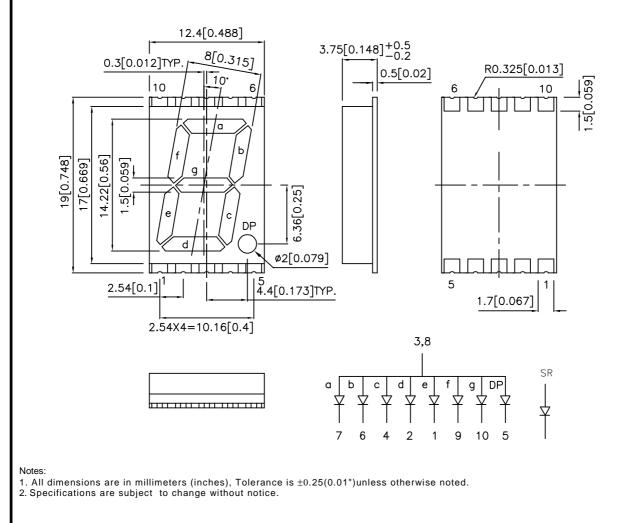
Features

- •0.56INCH DIGIT HEIGHT.
- •LOW CURRENT OPERATION.
- •EXCELLENT CHARACTER APPEARANCE.
- ●I.C. COMPATIBLE.
- •MECHANICALLY RUGGED.
- •GRAY FACE, WHITE SEGMENT.
- •PACKAGE:800PCS/ REEL.

Description

The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



SPEC NO: DSAA6032 APPROVED: J. Lu

REV NO: V.4 CHECKED: Joe Lee DATE: MAR/24/2005 DRAWN: Y.CHENG

Selection Guide								
Part No.	Dice	Lens Type	lv (ucd) @ 10mA		Description			
			Min.	Тур.				
KPSA56-104	SUPER BRIGHT RED (GaAIAs)	WHITE DIFFUSED	3000	15500	Common Anode,Rt. Hand Decimal.			

Electrical / Optical Characteristics at TA=25°C

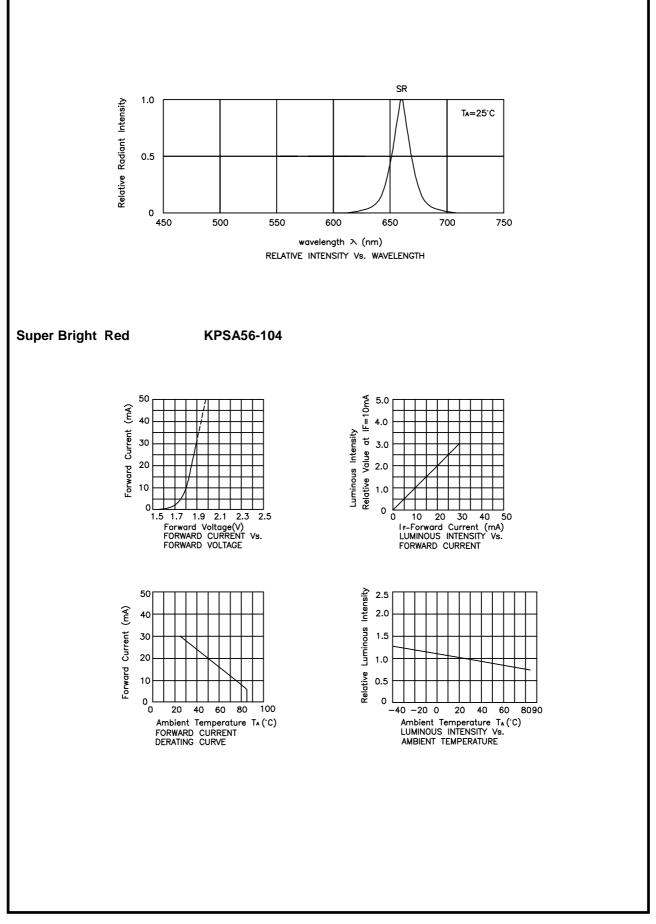
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Red	660		nm	IF=20mA
λD	Dominant Wavelength	Super Bright Red	640		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Red	20		nm	IF=20mA
С	Capacitance	Super Bright Red	45		pF	VF=0V;f=1MHz
Vf	Forward Voltage	Super Bright Red	1.85	2.5	V	IF=20mA
IR	Reverse Current	Super Bright Red		10	uA	VR = 5V

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Red	Units
Power dissipation	100	mW
DC Forward Current	30	mA
Peak Forward Current [1]	155	mA
Reverse Voltage	5	V
Operating / Storage Temperature -40°C To +85°C		

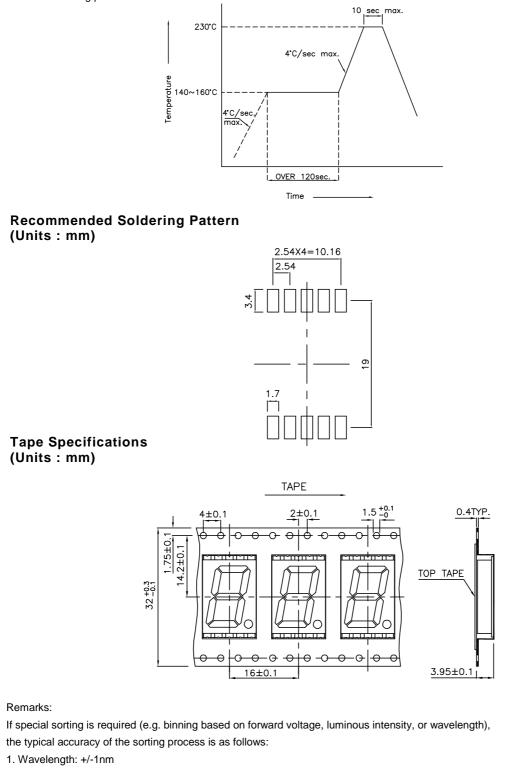
Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.



KPSA56-104 SMT Reflow Soldering Instructions

Number of reflow process shall be 2 times or less and cooling process to normal temperature is required between first and second soldering process.



- 2. Luminous Intensity: +/-15%
- 3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.

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